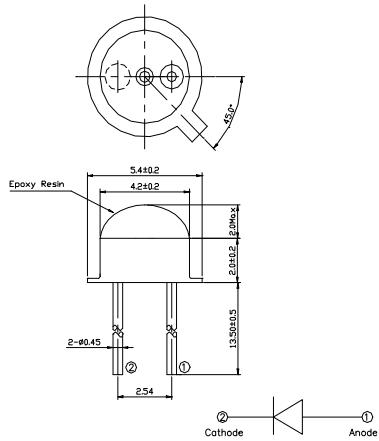


## 1. Scope

The KSP-1MLR2, a silicon photodiode mounted in a TO-18 type header with black epoxy encapsulation, provides wide angular response and is relatively low-cost as compared to TO-18 can-type devices.

## 2. Features

- Wide angular response
- Low profile package
- Relatively low-cost against metal can package



## 3. Applications

- Optical detectors
- Infrared sensors
- Smoke detectors

## 4. Package Outline

See the attached Drawing No. PD-KSP1MLR2-OT-01

## 5. Absolute Maximum Ratings

[Ta = 25 ]

Item	Symbol	Ratings	Unit
Reverse Voltage	V <sub>R</sub>	20	V
Operating Temperature	T <sub>opr.</sub>	-25 ~ +90	
Storage Temperature	T <sub>stg.</sub>	-30 ~ +100	
Soldering Temperature	T <sub>sol.</sub>	260	

## 6. Electro-optical Characteristics

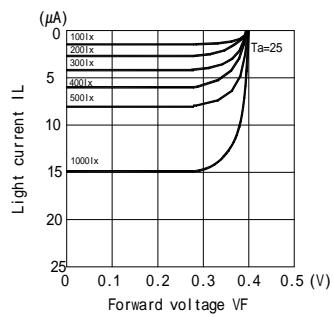
[Ta = 25 ]

Item	Symbol	Condition	Min.	Typ.	Max.	Unit
Open circuit voltage	V <sub>oc</sub>	Ev=1,000lx *1		0.4		V
Short circuit current	I <sub>sc</sub>		8	11		μA
Dark current	I <sub>d</sub>	V <sub>R</sub> =5V			0.1	μA
Capacitance	C <sub>t</sub>			50		pF
Temperature coefficient of V <sub>oc</sub>	t	V=0V, f=1MHz		-2.2		V
Temperature coefficient of I <sub>sc</sub>	t			0.18		MHz
Spectral sensitivity			700~1,050			nm
Peak wavelength	p			900		nm
Half angle				±60		deg.

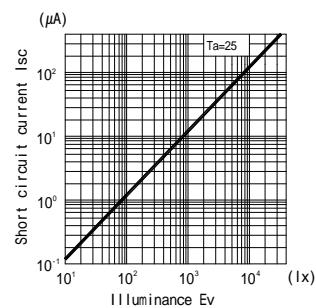
\*1. Color temp.=2856K standard Tungsten lamp

## 7. Typical Electrical-optical Characteristics Curves

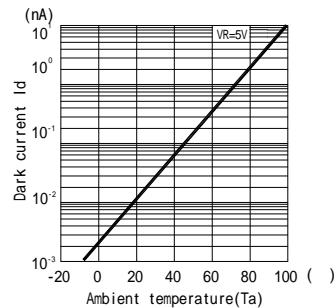
**Light current Vs.  
Forward voltage**



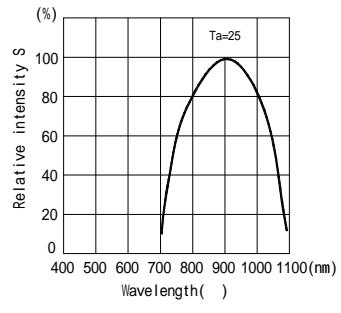
**Short circuit current Vs.  
Illuminance**



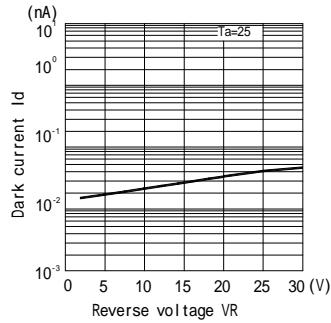
**Dark current Vs.  
Ambient temperature**



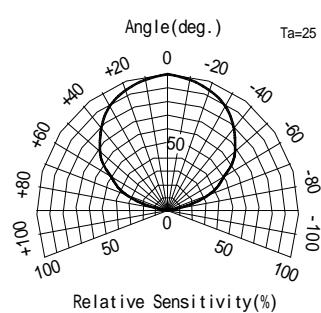
**Relative sensitivity Vs.  
Wavelength**



**Dark current Vs.  
Reverse voltage**



**Radiant Pattern.**



**Capacitance between terminal Vs.  
Reverse voltage**

